



PATENT Customer No. 22,852 Attorney Docket No. 04329.3139-00

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re A	Application of:	
Mitsuaki IZUHA et al.		Group Art Unit: 2811
Application No.: 10/660,555		Examiner: Vu, Quang D.
Filed:	September 12, 2003	
For:	MOSFET FORMED BY USING SALICIDE PROCESS AND METHOD OF	
	MANUFACTURING THE SAME	

Commissioner for Patents and Trademarks P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

## **RESPONSE TO RESTRICTION REQUIREMENT**

In the Office Action dated June 25, 2004, with a period for response extending through July 25, 2004, the Examiner required restriction under 35 U.S.C. § 121 between the following groups of claims:

Group I - Claims 1-6, characterized by the Examiner as drawn to a semiconductor device; and

Group II - Claims 7-14, characterized by the Examiner as drawn to a method of manufacturing a semiconductor device.

Applicants provisionally elect to prosecute the group characterized by the Examiner as Group I, claims 1-6, without traverse.

Please grant any extensions of time required to enter this response and charge any additional required fees to our Deposit Account No. 06-0916.

Respectfully submitted,

FINNEGAN, HENDERSON, FARABOW, GARRETT & DUNNER, L.L.P.

Dated: July 20, 2004

Rajeev Gupta

Reg. No. 55,873